
2SC4693

Silicon NPN Epitaxial Planar

HITACHI

ADE-208-1119 (Z)

1st. Edition

Mar. 2001

Application

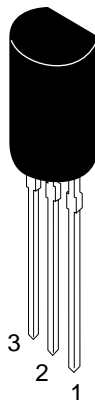
VHF Wide band amplifier

Features

- High gain bandwidth product
 $f_T = 2.5 \text{ GHz Typ.}$
- Large collector power dissipation
 $P_C = 900 \text{ mW}$

Outline

TO-92MOD



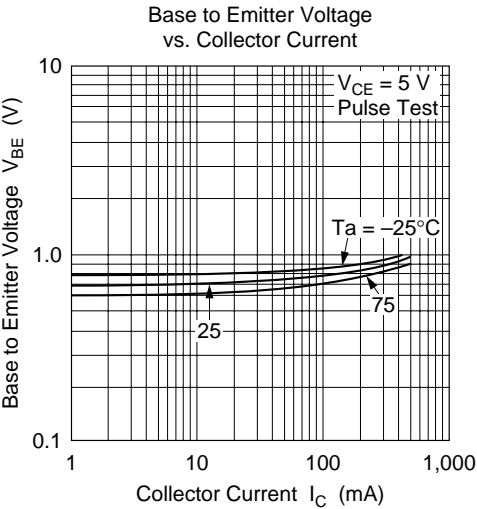
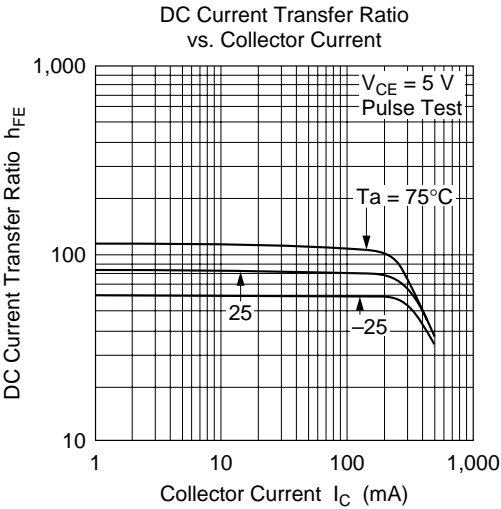
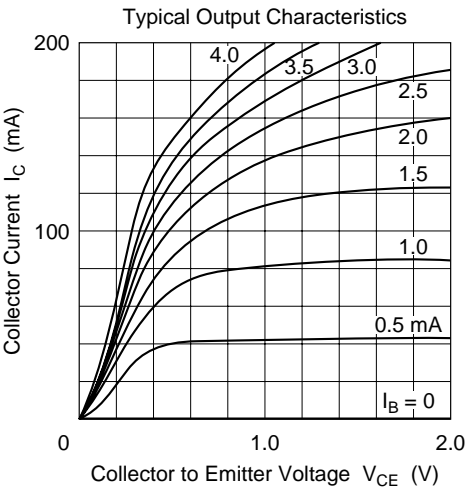
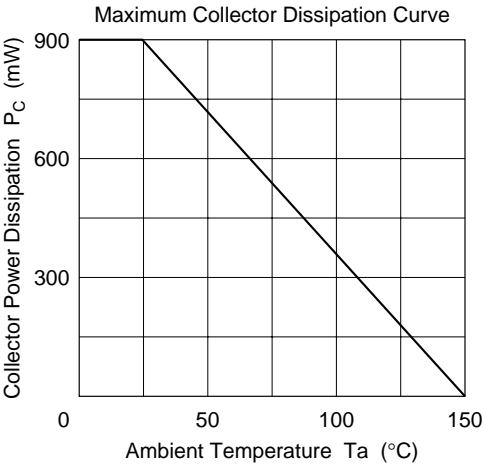
1. Emitter
2. Collector
3. Base

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

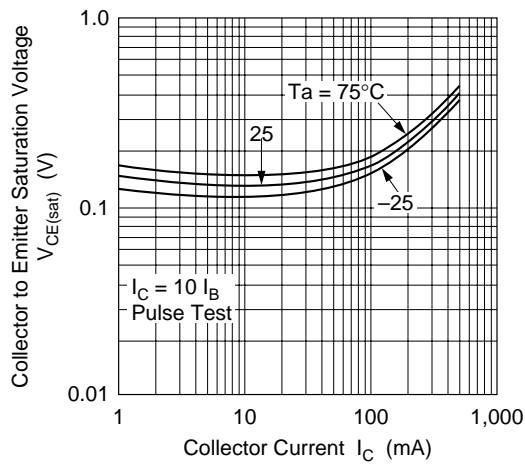
Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	30	V
Collector to emitter voltage	V_{CEO}	20	V
Emitter to base voltage	V_{EBO}	3	V
Collector current	I_{C}	300	mA
Collector peak current	$i_{\text{C (peak)}}$	500	mA
Collector power dissipation	P_{C}	900	mW
Junction temperature	T_{j}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Electrical Characteristics ($T_a = 25^\circ\text{C}$)

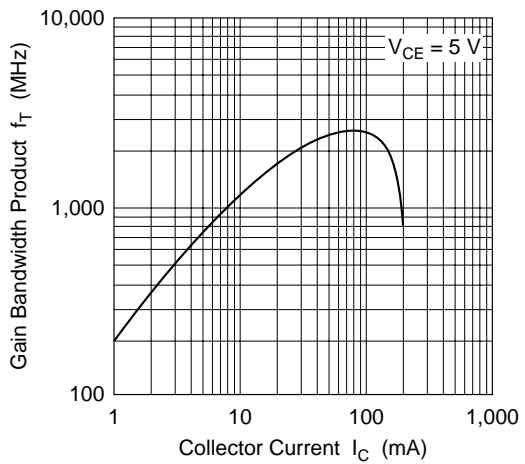
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	30	—	—	V	$I_{\text{C}} = 100\ \mu\text{A}$, $I_{\text{E}} = 0$
Collector to emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	20	—	—	V	$I_{\text{C}} = 1\ \text{mA}$, $R_{\text{BE}} = \infty$
Collector cutoff current	I_{CBO}	—	—	1.0	μA	$V_{\text{CB}} = 25\ \text{V}$, $I_{\text{E}} = 0$
Emitter cutoff current	I_{EBO}	—	—	10	μA	$V_{\text{EB}} = 3\ \text{V}$, $I_{\text{C}} = 0$
DC current transfer ratio	h_{FE}	50	—	200		$V_{\text{CE}} = 5\ \text{V}$, $I_{\text{C}} = 50\ \text{mA}$
Gain bandwidth product	f_{T}	1.5	2.5	—	GHz	$V_{\text{CE}} = 5\ \text{V}$, $I_{\text{C}} = 50\ \text{mA}$
Collector output capacitance	C_{ob}	—	4.5	—	pF	$V_{\text{CB}} = 10\ \text{V}$, $I_{\text{E}} = 0$, $f = 1\ \text{MHz}$



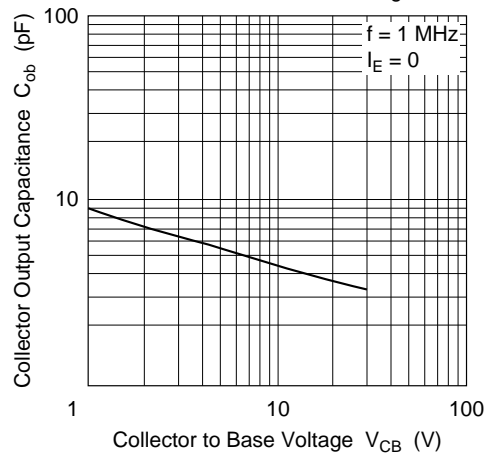
Collector to Emitter Saturation Voltage
vs. Collector Current



Gain Bandwidth Product
vs. Collector Current

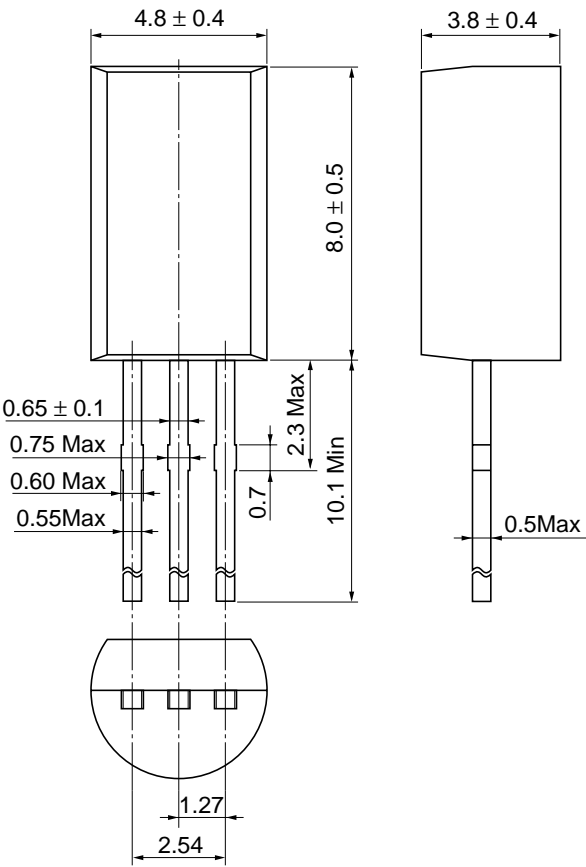


Collector Output Capacitance
vs. Collector to Base Voltage



Package Dimensions

As of January, 2001
Unit: mm



Hitachi Code	TO-92 Mod
JEDEC	—
EIAJ	Conforms
Mass (reference value)	0.35 g

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